

Absolute Maximum Ratings (Over operating free-air temperature range)

| Parameter | Min. | Max. | Units |
|--|------|-------|-------|
| Storage temperature | -65 | 150 | |
| Ambient Temperature with Power Applied | -40 | 85 | °C |
| Supply Voltage to Ground Potential (Inputs & V _{CC} Only) | -0.5 | 7.0 | |
| Supply Voltage to Ground Potential (Outputs & D/O Only) | -0.5 | 7.0 V | |
| DC Input Voltage | -0.5 | 7.0 | |
| DC Output Current | - | 120 | mA |
| Power Dissipation | - | 500 | mW |

Stress beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device.

DC Electrical Characteristics (Over the Operating Range, $T_A = -40$ °C to +85°C, $V_{CC} = 5V \pm 5\%$)

| Parameters | Description | Test Conditions(1) | Min | Typ (2) | Max | Units | |
|---------------------|-------------------------------------|---|------|---------|------|-------|--|
| V _{ANALOG} | Analog Signal Range | 0 | | | 2.0 | | |
| V_{IH} | Input HIGH Voltage | Guaranteed Logic HIGH level 2.0 | | | | V | |
| V_{IL} | Input LOW Voltage | Guaranteed Logic LOW Level | -0.5 | | 0.8 | 7 | |
| I_{IH} | Input HIGH Current | $V_{CC} = Max., V_{IN} = V_{CC}$ | | ±1 | | | |
| I_{IL} | Input LOW Current | V _{CC} = Max., V _{IN} = GND | | | ±1 | | |
| I _O | Analog Output Leakage Currnet | $0 \le S1$, S2, or $D \le V_{CC}$, Switch OFF | | | ±1 | μΑ | |
| V _{IK} | Clamp Diode Voltage | $V_{CC} = Min., I_{IN} = -18mA$ | | -0.7 | -1.2 | V | |
| Ios | Short Circuit Current(3) | $S1, S2, D = 0V V_{CC}$ | 100 | | | mA | |
| V_{H} | Input Hysteresis at Control Pins | | | 150 | | mV | |
| Ron | Switch On-Resistance | $V_{CC} = MIN., V_{OUT} = 0.975V \; R_L = 75\Omega, I_{ON} = 13 \; mA$ | | 3 | 7 | Ω | |
| | | V_{CC} = MIN., V_{OUT} = 1.95V R_L = 75 Ω , I_{ON} = 26 mA | | 7 | 10 | 2.2 | |

Notes:

- 1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
- 2. Typical values are at $V_{\rm CC}$ = 5.0V, TA = 25°C ambient and maximum loading.
- 3. Not more than one output should be shorted at one time. Duration of the test should not exceed one second.
- 4. Measured by the voltage drop between S1, S2, and D I/O pins at indicated current through the switch. On-Resistance is determined by the lower of the voltages on the S1, S2, and D I/O pins.



Dynamic Characteristics (Over the Operating Range, $T_A = -40$ °C to +85°C, $V_{CC} = 5V \pm 5\%$)

| Parameters | Description | Test Conditions ⁽¹⁾ | Min | Тур | Max | Units |
|---------------------------------|--------------------------|--|--|------|-----|-------|
| T _{ON} | Turn On Time | $R_L = 70\Omega$, $C_L = 20$ PF, See Fig. 2 | | 2.5 | 5 | |
| T _{OFF} | Turn Off Time | $R_L = 70\Omega$, $C_L = 20$ PF, See Fig. 2 | $R_L = 70\Omega$, $C_L = 20$ PF, See Fig. 2 | | 5 | ns |
| BW ⁽¹⁾ | -3dB Bandwidth | $R_L = 150\Omega$, See Fig. 3 | 150 | | | MHz |
| X _{TALK} | Crosstalk | RIN = $10Ω$; R _L = $150Ω$, $10MHz$, See Fig. 3 -58 | | | dB | |
| D_{G} | Differential Gain | $R_L = 150\Omega$, $f = 3.58$ MHz, See Fig. 1 | | 0.64 | | % |
| D _P | Differential Phase | $R_L = 150\Omega$, $f = 3.58$ MHz, See Fig. 1 | | 0.27 | | Deg. |
| $C_{IN}^{(1)}$ | Input/Enable Capacitance | $V_{IN} = 0V, f = 1 MHz$ | | | 6 | |
| C _{OFF} ⁽¹⁾ | Capacitance, Switch Off | $V_{IN} = 0V, f = 1 MHz$ | | | 6 | pF |
| C _{ON} ⁽¹⁾ | Capacitance, Switch On | $V_{IN} = 0V, f = 1 MHz$ | | | 20 | |
| O _{IRR} | Off Isolation | $R_L = 150\Omega$, 10MHz, See Fig 3 -38 | | | dB | |

Notes:

Power Supply Characteristics

| Parameters | Description | Test Conditions ⁽¹⁾ | | Min | Typ (2) | Max | Units |
|------------------|--|--|-----------------------------|-----|---------|------|------------|
| I_{CC} | Quiescent Power Supply Current | V _{CC} = Max. | IN = GND or V _{CC} | | 0.1 | 3.0 | μΑ |
| ΔI_{CC} | Supply Current per Input @ TTL HIGH | V _{CC} = Max. | $IN = 3.4V^{(3)}$ | | | 2.5 | mA |
| I _{CCD} | Supply Current per Input per MHz ⁽⁴⁾ | V_{CC} = Max., S1, S2 and D Pins Open \overline{EN} = GND Control Input Toggling 50% Duty Cycle | | | | 0.25 | mA/ MHz |

Notes:

- 1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device.
- 2. Typical values are at V_{CC} = 5.0V, +25°C ambient and maximum loading.
- 3. Per TTL driven input (V_{IN} = 3.4V, control inputs only); S1, S2, and D pins do not contribute to Icc.
- 4. This current applies to the control inputs only and represent the current required to switch internal capacitance at the specified frequency. The S1, S2, and D I/O pins generate no significant AC or DC currents as they transition. This parameter is not tested, but is guaranteed by design.

^{1.} This parameter is determined by device characterization but is not production tested.



Definitions

| Parameters | Description |
|-----------------------------------|---|
| T _{ON} | Resistance between source and drain with switch in the ON state. |
| Io | Output leakage current measured at S1, S2, and D with the switch OFF. |
| V _{IN} | Digital voltage at the IN pin that selects between S1 and S2 analog inputs. |
| $V_{\rm EN}$ | A voltage that ENABLES the chip. |
| C _{IN} | Capacitance at the digital inputs. |
| C _{OFF} | Capacitance at analog I/O (S1, S2, D) with switch OFF. |
| Con | Capacitance at analog I/O (S1, S2, D) with switch ON. |
| V _{IH} | Minimum input voltage for logic HIGH. |
| V _{IL} | Minimum input voltage for logic LOW. |
| I _{IH} (I _{IL)} | Input current of the digital input. |
| I _{OS} | Minimum short circuit current for S1, S2 and D. |
| ton | Propagation delay measured between 50% of the digital input to 90% of the analog output when switch is turned ON. The peak analog voltage is 0.714V. |
| t _{OFF} | Propagation delay measured between 50% of the digital input to 90% of the analog output when switch is turned OFF. The peak analog voltage is 0.714V. |
| Bw | Frequency response of the switch in the ON state measured at 3dB down. |
| X _{TALK} | Is an unwanted signal coupled from channel to channel. Measured in $-dB$. $X_{TALK} = 20$ LOG V_{OUT}/V_{IN} . This is non-adjacent crosstalk. |
| D_{G} | Differential gain is the difference measurement between two bias levels, for instance analog input signals of 0V to 0.714V. |
| D_P | Differential phase is the difference measurement between two bias levels, for instance analog input signals of 0V to 0.714V. |
| O _{IRR} | Off isolation is the resistance (measured in -dB) between the input and output with the switch off (NO). |



Test Circuits

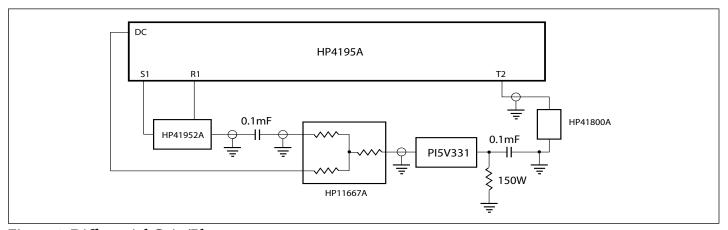


Figure 1. Differential Gain/Phase

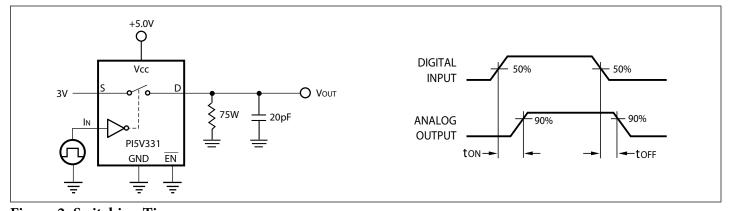


Figure 2. Switching Time

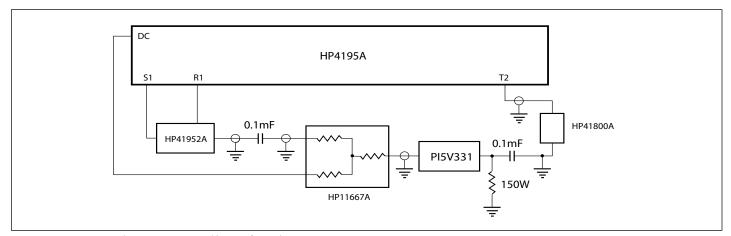
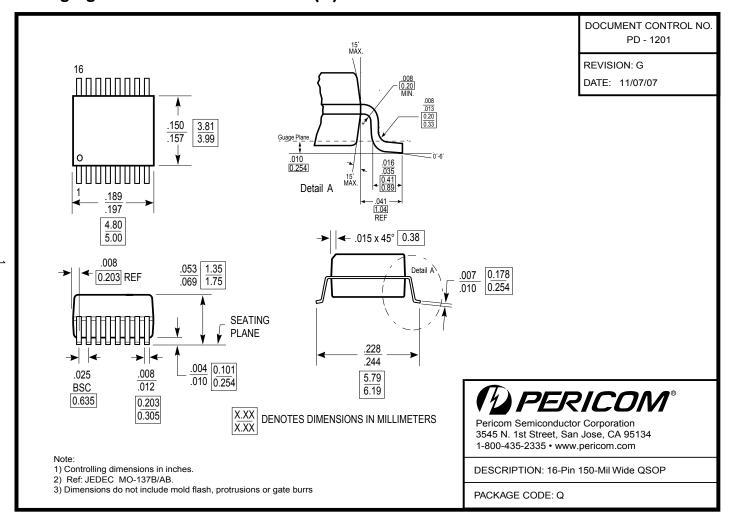


Figure 3. Gain/Phase, Crosstalk, Off-Isolation



Packaging Mechanical: 16-Pin QSOP (Q)



Ordering Information

| Ordering Code | Package Code | Package Type |
|---------------|--------------|---|
| PI5V331QE | Q | Pb-free & Green, 16-pin 150-mil wide QSOP |

- 1. Thermal characteristics can be found on the company web site at www.pericom.com/packaging/
- 2. "E" denotes Pb-free and Green
- 3. Adding an "X" at the end of the ordering code denotes tape and reel packaging